MRF10005

ΜΑζΟΜ

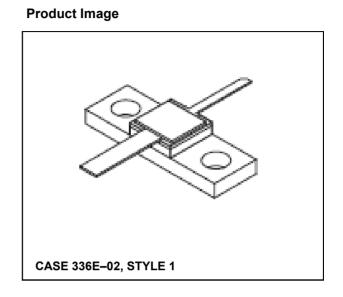
Microwave Power Silicon Bipolar Transistor 5.0 W, 960–1215 MHz, 28V

Features

- Guaranteed performance @1.215GHz, 28Vdc
- Output power: 5.0W CW
- Minimum gain = 8.5dB, 10.3dB (Typ.)
- RF performance curves for 28 Vdc and 36 Vdc operation
- 100% tested for load mismatch at all phase angles with 10:1 VSWR
- · Hermetically sealed industry standard package
- Silicon nitride passivated
- Gold metallized, emitter ballasted for long life and resistance to metal migration
- Internal input matching for broadband operation

Description and Applications

Designed for CW and long-pulsed common base amplifier applications, such as JTIDS and Mode S, in the 0.96 to 1.215 GHz frequency range with high overall duty cycles.



V _{CES} V _{CBO}	55 55	Vdc Vdc
	55	Vdc
		vuc
V _{EBO}	3.5	Vdc
Ιc	1.25	mAdc
PD	25 143	Watt mW/°C
T _{stg}	-65 to +200	°C
TJ	200	°C
	PD	PD 25 143 Tstg -65 to +200

Thermal Resistance, Junction to Case (2)
NOTES:

1. These devices are designed for RF operation. The total device dissipation rating applies only when the devices are operated as RF amplifiers.

Symbol

R_{ejc}

Max

7.0

Unit

°C/W

2. Thermal Resistance is determined under specified RF operating conditions by infrared measurement techniques.

Characteristic

M/A-COM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit www.macom.com for additional data sheets and product information.

Rev. V1

¹

MRF10005

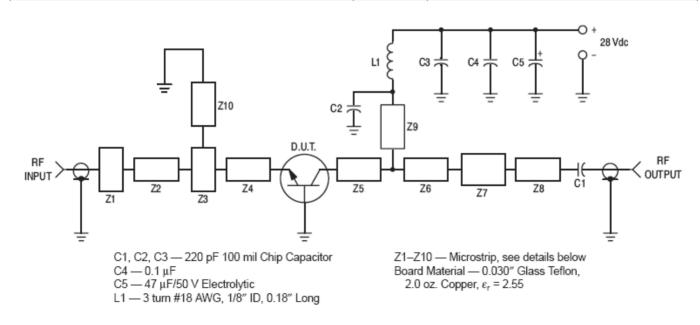
Microwave Power Silicon Bipolar Transistor 5.0 W, 960–1215 MHz, 28V



Rev. V1

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS						
Collector-Emitter Breakdown Voltage (I _C = 25 mAdc, V _{BE} = 0)	V _{(BR)CES}	55	—	—	Vdc	
Collector–Base Breakdown Voltage (I _C = 25 mAdc, I _E = 0)	V _{(BR)CBO}	55	—	_	Vdc	
Emitter–Base Breakdown Voltage (I _E = 0.5 mAdc, I _C = 0)	V _{(BR)EBO}	3.5	—	_	Vdc	
Collector Cutoff Current (V _{CB} = 28 Vdc, I _E = 0)	I _{сво}	_	—	1.0	mAdc	
ON CHARACTERISTICS						
DC Current Gain (I _C = 500 mAdc, V _{CE} = 5.0 Vdc)	h _{FE}	20	_	100	_	
DYNAMIC CHARACTERISTICS						
Output Capacitance (V _{CB} = 28 Vdc, I _E = 0, f = 1.0 MHz)	Cob	_	7.0	10	pF	
FUNCTIONAL TESTS						
Common–Base Amplifier Power Gain (V _{CC} = 28 Vdc, P _{out} = 5.0 W, f = 1215 MHz)	G _{PB}	8.5	10.3	_	dB	
Collector Efficiency (V _{CC} = 28 Vdc, P _{out} = 5.0 W, f = 1215 MHz)	η	45	55	_	%	
Load Mismatch (V _{CC} = 28 Vdc, P _{out} = 5.0 W, f = 1215 MHz, VSWR = 10:1 All Phase Angles)	Ψ	No Degradation in Output Power				



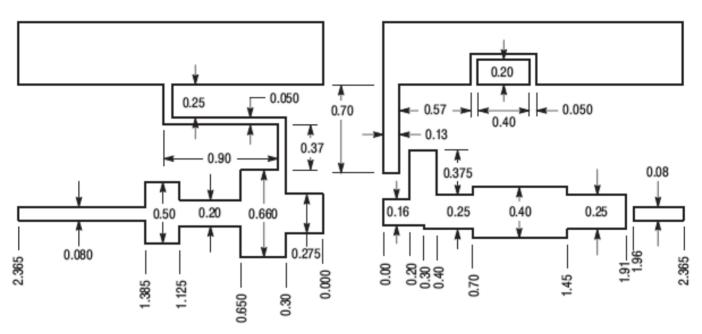
2

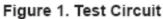
M/A-COM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit <u>www.macom.com</u> for additional data sheets and product information.



Microwave Power Silicon Bipolar Transistor 5.0 W, 960–1215 MHz, 28V

Rev. V1





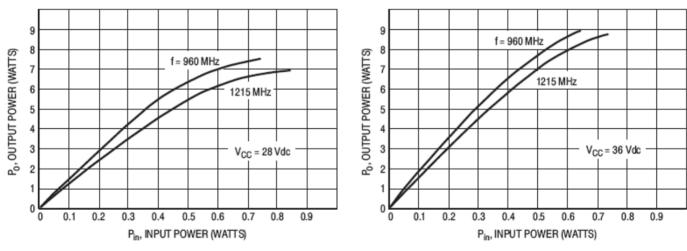


Figure 2. Output Power versus Input Power

Figure 3. Output Power versus Input Power

3

M/A-COM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit www.macom.com for additional data sheets and product information.

MRF10005

Microwave Power Silicon Bipolar Transistor 5.0 W, 960-1215 MHz, 28V

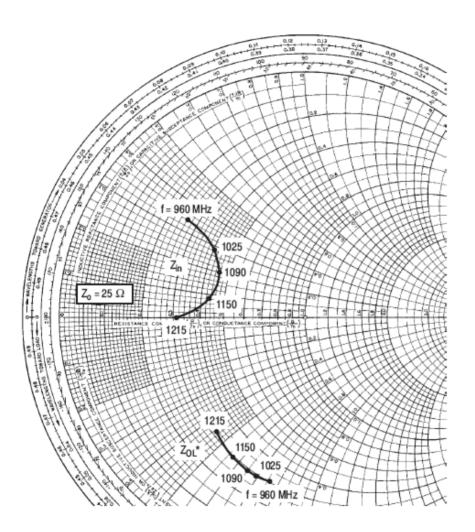


Figure 4. Series Equivalent Input/Output Impedances



Rev. V1

Pout = 5 W, V_{CC} = 28 V

00. 00								
f	Z _{in}	Z _{OL} *						
MHz	OHMS	OHMS						
960	6.5 + j8.5	7.4 - j18.9						
1025	10.0 + j7.0	7.2 - j17.4						
1090	11.2 + j4.9	7.1 - j16.3						
1150	10.8 + j2.0	7.15 - j14.3						
1215	7.8 + j0.0	7.8 - j11.2						

ZoL* = Conjugate of the optimum load impedance into which the device output operates at a given output power, voltage and frequency.

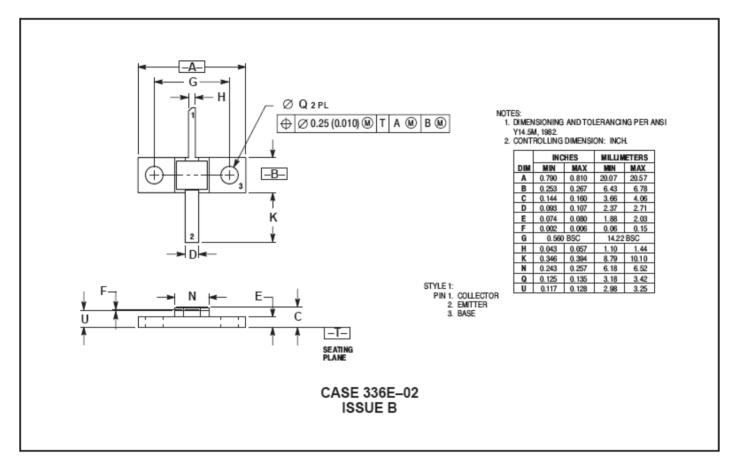
M/A-COM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit <u>www.macom.com</u> for additional data sheets and product information.

4



Microwave Power Silicon Bipolar Transistor 5.0 W, 960–1215 MHz, 28V

PACKAGE DIMENSIONS



M/A-COM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit www.macom.com for additional data sheets and product information.





Rev. V1

M/A-COM Technology Solutions Inc. All rights reserved.

Information in this document is provided in connection with M/A-COM Technology Solutions Inc ("MACOM") products. These materials are provided by MACOM as a service to its customers and may be used for informational purposes only. Except as provided in MACOM's Terms and Conditions of Sale for such products or in any separate agreement related to this document, MACOM assumes no liability whatsoever. MACOM assumes no responsibility for errors or omissions in these materials. MACOM may make changes to specifications and product descriptions at any time, without notice. MACOM makes no commitment to update the information and shall have no responsibility whatsoever for conflicts or incompatibilities arising from future changes to its specifications and product descriptions. No license, express or implied, by estoppels or otherwise, to any intellectual property rights is granted by this document.

THESE MATERIALS ARE PROVIDED "AS IS" WITHOUT WARRANTY OF ANY KIND, EITHER EXPRESS OR IMPLIED, RELATING TO SALE AND/OR USE OF MACOM PRODUCTS INCLUDING LIABILITY OR WARRANTIES RELATING TO FITNESS FOR A PARTICULAR PURPOSE, CONSEQUENTIAL OR INCIDENTAL DAMAGES, MERCHANTABILITY, OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT. MACOM FURTHER DOES NOT WARRANT THE ACCURACY OR COMPLETENESS OF THE INFORMATION, TEXT, GRAPHICS OR OTHER ITEMS CONTAINED WITHIN THESE MATERIALS. MACOM SHALL NOT BE LIABLE FOR ANY SPECIAL, INDIRECT, INCIDENTAL, OR CONSEQUENTIAL DAMAGES, INCLUDING WITHOUT LIMITATION, LOST REVENUES OR LOST PROFITS, WHICH MAY RESULT FROM THE USE OF THESE MATERIALS.

MACOM products are not intended for use in medical, lifesaving or life sustaining applications. MACOM customers using or selling MACOM products for use in such applications do so at their own risk and agree to fully indemnify MACOM for any damages resulting from such improper use or sale.

⁶

M/A-COM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit www.macom.com for additional data sheets and product information.